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|---------------|--|---------------|-------------------|------------|
| FORM PTO-1449 | | ATTY. DKT NO. | 01-235 | SER. NO. |
| | | APPLICANT | NAITO et al. | |
| | | FILING DATE | December 10, 2001 | GROUP 1775 |

16775 US 6135 PRO 12/10/03

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

| EXAMINER INITIAL | | DOCUMENT NUMBER | DATE | NAME | CLASS | SUB CLASS |
|------------------|--|---|---------------|-----------------|-------|-----------|
| SSS | | 5,679,153 (Discussed on page 2 of the spec.) | Oct. 21, 1997 | Dmitriev et al. | | 16775 |
| SSS | | 6,153,165 (Corresponding to JP-A-10-324600 which is discussed on page 2 of the spec.) | Nov. 28, 2000 | Tanino et al. | | |
| SSS | | 6,214,108 (Corresponding to JP-A-2000-44398 which is discussed on page 2 of the spec.) | Apr. 10, 2001 | Okamoto et al. | | |
| SSS | | 6,153,166 | Nov. 28, 2000 | Tanino | | |
| SSS | | 6,203,772 | Mar. 20, 2001 | Tanino et al. | | |

FOREIGN PATENT DOCUMENTS

TRANSLATION

| | | DOCUMENT NUMBER | DATE | COUNTRY | NAME | CLASS | SUB CLASS | YES | NO |
|-----|--|-------------------|--------|---------|------|-------|-----------|-----|----|
| SSS | | JP-A-2000-34198 * | 2/2/00 | JAPAN | | | | X | |
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* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at <http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX>.

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

| | | |
|----------|--|---|
| SSS | | Kamata et al., "Migration of shifting in epitaxial growth of thick 4H-SiC," <u>Abstract of the Lecture of 47th Japan Society of Applied Physics Related Association</u> , separate Volume 1, p.407, No. 29p-YF-6, March 2000. (Discussed on page 2 of the spec.) |
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| EXAMINER | | DATE CONSIDERED |

Stephen Stein

6/23/03